

FMG1G150US60LE

Molding Type Module

General Description

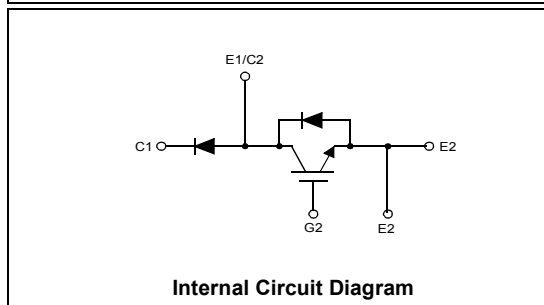
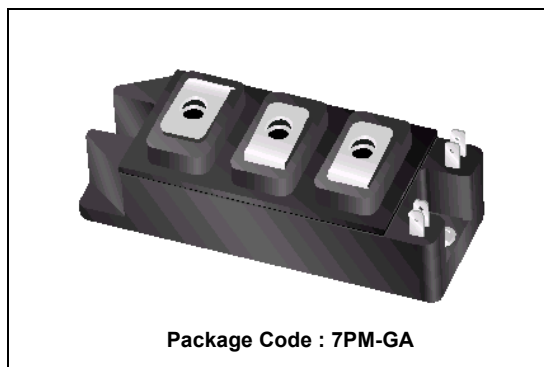
Fairchild IGBT Power Module provides low conduction and switching losses as well as short circuit ruggedness. It's designed for the applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short-circuit ruggedness is required.

Features

- Short Circuit Rated Time; 10us @ $T_C = 100^\circ\text{C}$, $V_{GE} = 15\text{V}$
- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)} = 2.1\text{V}$ @ $I_C = 150\text{A}$
- High Input Impedance
- Fast & Soft Anti-Parallel FWD
- UL Certified No.E209204

Application

- AC & DC Motor Controls
- General Purpose Inverters
- Robotics
- Servo Controls
- UPS



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	FMG1G150US60LE	Units
V_{CES}	Collector-Emitter Voltage	600	V
V_{GES}	Gate-Emitter Voltage	± 20	V
I_C	Collector Current @ $T_C = 80^\circ\text{C}$	150	A
$I_{CM(1)}$	Pulsed Collector Current	300	A
I_F	Diode Continuous Forward Current @ $T_C = 80^\circ\text{C}$	150	A
I_{FM}	Diode Maximum Forward Current	300	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	595	W
T_{SC}	Short Circuit Withstand Time @ $T_C = 100^\circ\text{C}$	10	us
T_J	Operating Junction Temperature	-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-40 to +125	$^\circ\text{C}$
V_{ISO}	Isolation Voltage @ AC 1minute	2500	V
Mounting Torque	Power Terminal Screw : M5	4.0	N.m
	Mounting Screw : M6	4.0	N.m

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Electrical Characteristics of IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 250uA	600	--	--	V
ΔBV _{CES} /ΔT _J	Temperature Coeff. of Breakdown Voltage	V _{GE} = 0V, I _C = 1mA	--	0.6	--	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0V	--	--	250	uA
I _{GES}	Gate - Emitter Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0V	--	--	± 100	nA

On Characteristics

V _{GE(th)}	Gate - Emitter Threshold Voltage	I _C = 150mA, V _{CE} = V _{GE}	5.0	6.5	8.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 150A, V _{GE} = 15V	--	2.1	2.7	V

Switching Characteristics

t _{d(on)}	Turn-On Delay Time	V _{CC} = 300 V, I _C = 150A, R _G = 2Ω, V _{GE} = 15V, Inductive Load, T _C = 25°C	--	140	--	ns
t _r	Rise Time		--	80	--	ns
t _{d(off)}	Turn-Off Delay Time		--	120	--	ns
t _f	Fall Time		--	130	250	ns
E _{on}	Turn-On Switching Loss		--	2.3	--	mJ
E _{off}	Turn-Off Switching Loss	--	4.7	--	mJ	
t _{d(on)}	Turn-On Delay Time	V _{CC} = 300 V, I _C = 150A, R _G = 2Ω, V _{GE} = 15V, Inductive Load, T _C = 125°C	--	180	--	ns
t _r	Rise Time		--	90	--	ns
t _{d(off)}	Turn-Off Delay Time		--	150	--	ns
t _f	Fall Time		--	270	--	ns
E _{on}	Turn-On Switching Loss		--	3.1	--	mJ
E _{off}	Turn-Off Switching Loss	--	7.7	--	mJ	
T _{sc}	Short Circuit Withstand Time	V _{CC} = 300 V, V _{GE} = 15V @ T _C = 100°C	10	--	--	us
Q _g	Total Gate Charge	V _{CE} = 300 V, I _C = 150A, V _{GE} = 15V	--	460	--	nC
Q _{ge}	Gate-Emitter Charge		--	130	--	nC
Q _{gc}	Gate-Collector Charge		--	190	--	nC

Electrical Characteristics of DIODE T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units	
V _{FM}	Diode Forward Voltage	I _F = 150A	T _C = 25°C	--	1.9	2.8	V
			T _C = 100°C	--	1.8	--	
t _{rr}	Diode Reverse Recovery Time	I _F = 150A di / dt = 300 A/us	T _C = 25°C	--	90	130	ns
			T _C = 100°C	--	130	--	
I _{rr}	Diode Peak Reverse Recovery Current	I _F = 150A di / dt = 300 A/us	T _C = 25°C	--	15	20	A
			T _C = 100°C	--	22	--	
Q _{rr}	Diode Reverse Recovery Charge	I _F = 150A di / dt = 300 A/us	T _C = 25°C	--	675	1270	nC
			T _C = 100°C	--	1430	--	

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
R _{θJC}	Junction-to-Case (IGBT Part, per 1/2 Module)	--	0.21	°C/W
R _{θJC}	Junction-to-Case (DIODE Part, per 1/2 Module)	--	0.48	°C/W
R _{θJC}	Case-to-Sink (Conductive grease applied)	0.045	--	°C/W
Weight	Weight of Module	240	--	g

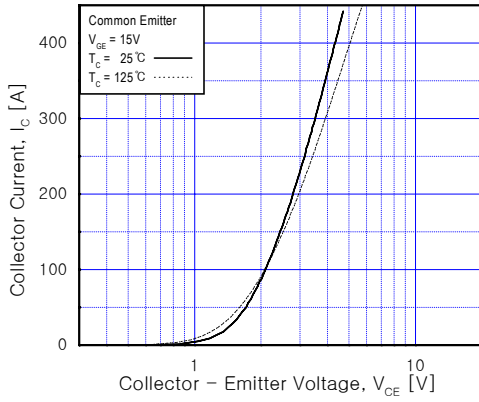


Fig 1. Typical Output Characteristics

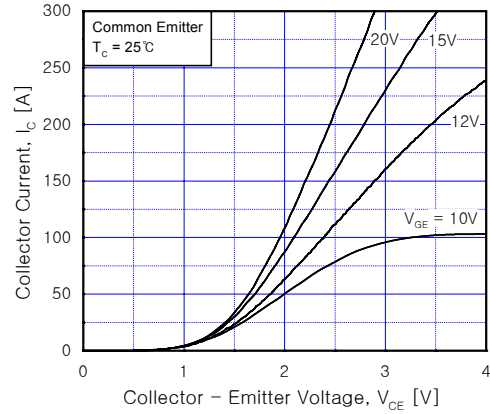


Fig 2. Typical Saturation Voltage Characteristics

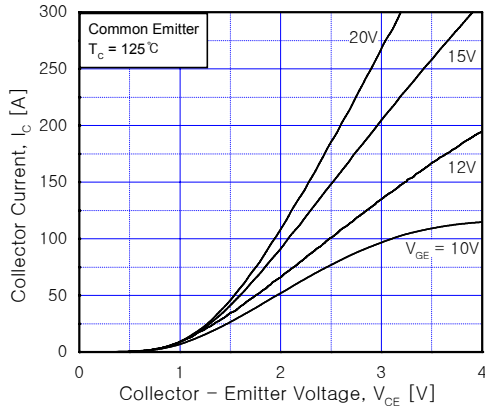


Fig 3. Typical Saturation Voltage Characteristics

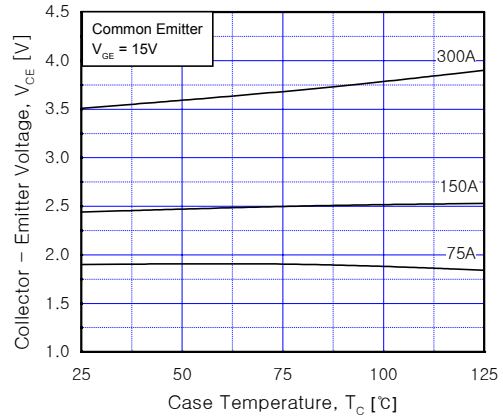


Fig 4. Saturation Voltage vs. Case Temperature at Variant Current Level

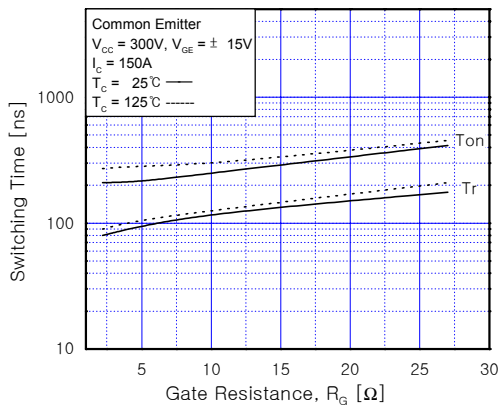


Fig 5. Turn-On Characteristics vs. Gate Resistance

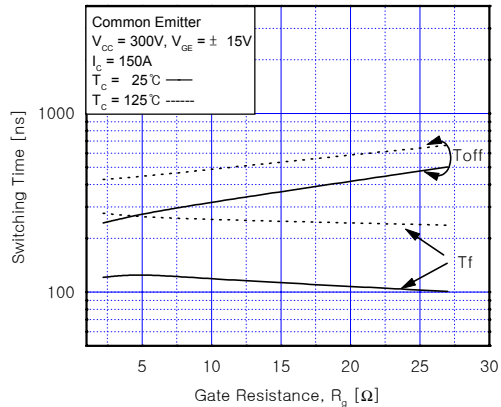


Fig 6. Turn-Off Characteristics vs. Gate Resistance

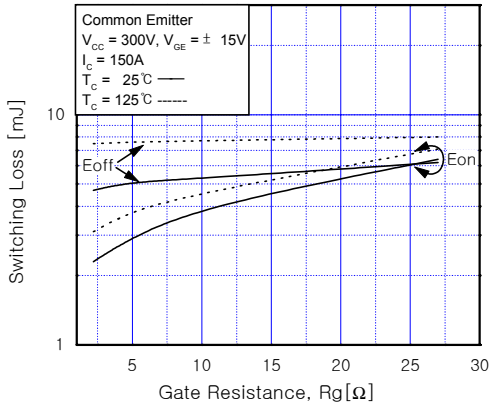


Fig 7. Switching Loss vs. Gate Resistance

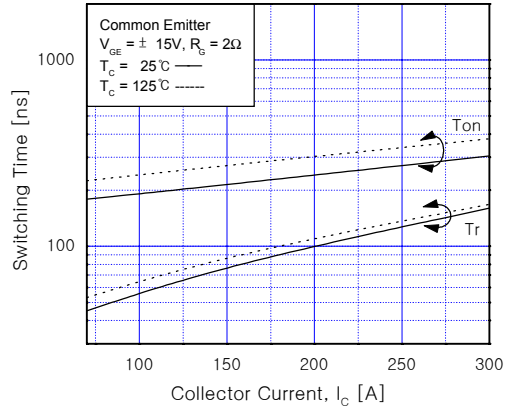


Fig 8. Turn-On Characteristics vs. Collector Current

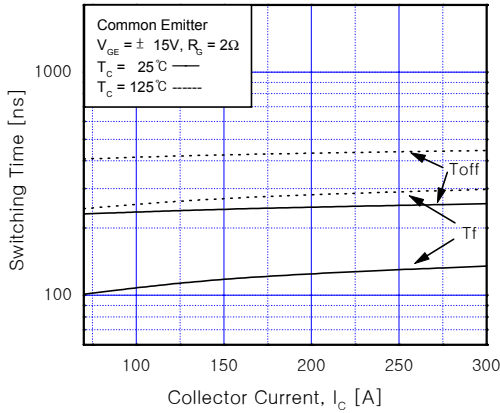


Fig 9. Turn-Off Characteristics vs. Collector Current

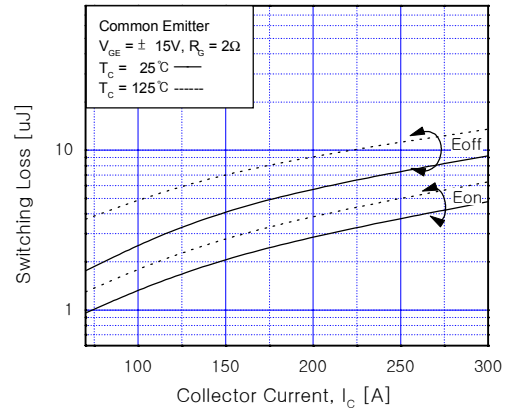


Fig 10. Switching Loss vs. Collector Current

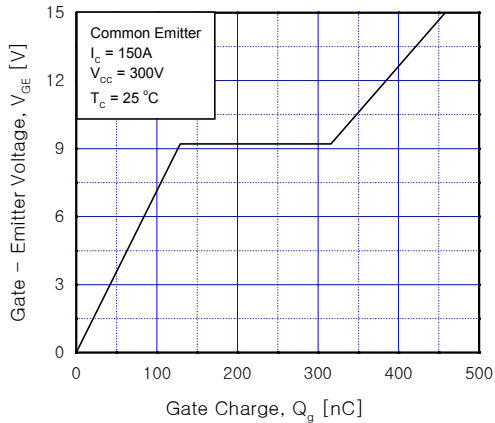


Fig 11. Gate Charge Characteristics

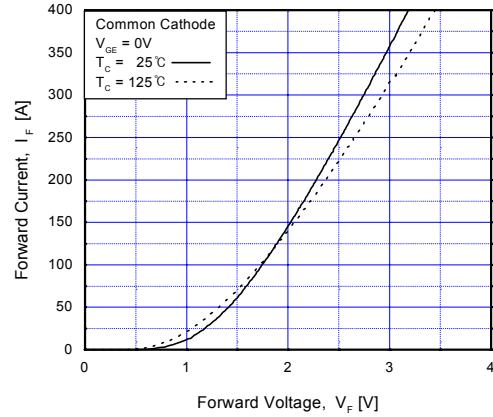


Fig 12. Forward Characteristics(diode)

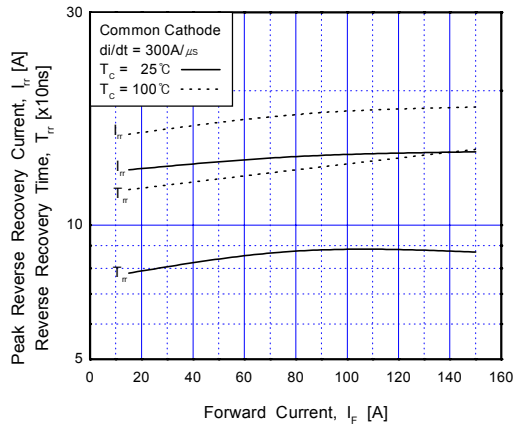
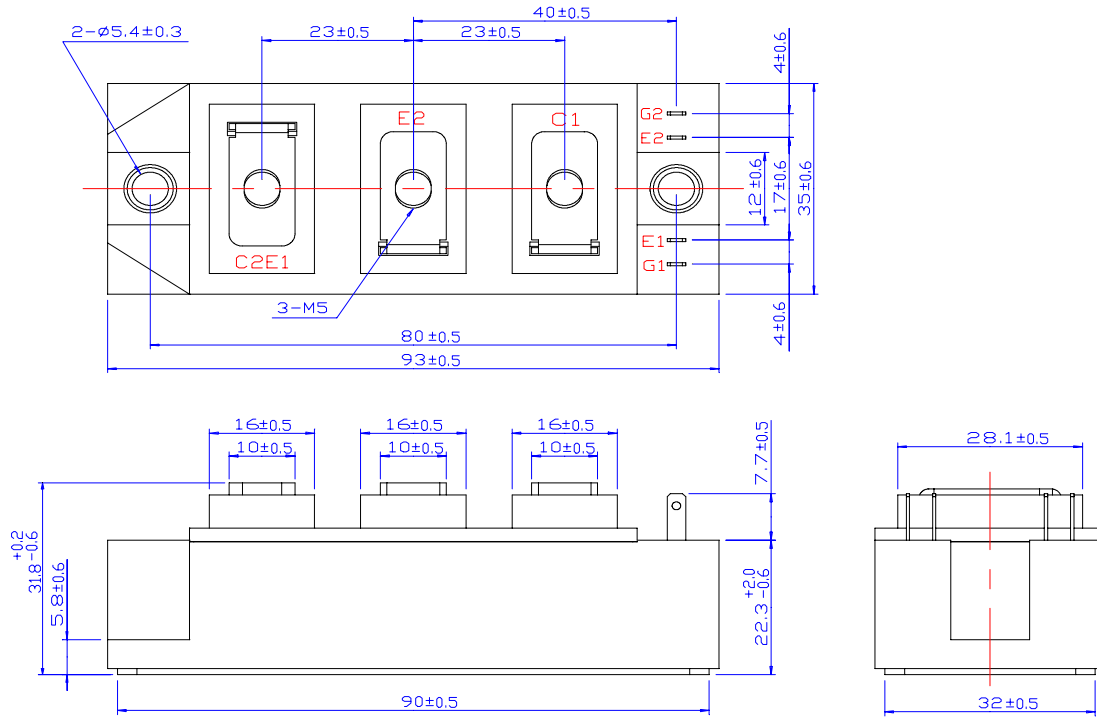


Fig 13. Reverse Recovery Characteristics(diode)

Package Dimension

7PM-GA



FMG1G150US60LE

Dimensions in Millimeters

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